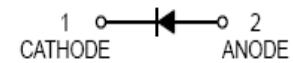
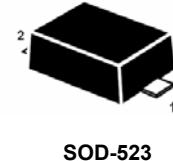


## Features

- Low forward voltage drop
- Fast switching
- PN junction guard ring for transient and ESD protection



Schematic Diagram

## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limits	Unit
DC Reverse Voltage	$V_R$	30	V
Continuous Forward Current	$I_F$	200	mA
Peak Forward Surge Current	$I_{FSM}$	600	mA
Total Power Dissipation	$P_{tot}$	200	mW
Total Resistance Junction to Ambient	$R_{eJA}$	635	°C/W
Junction Temperature	$T_J$	150	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR)R}$	30			V	$I_R=100\mu\text{A}$
Forward Voltage	$V_F$		0.22 0.41 0.52 0.29 0.35	0.24 0.5 0.8 0.32 0.40	V	$I_F=0.1\text{mA}$ $I_F=30\text{mA}$ $I_F=100\text{mA}$ $I_F=1.0\text{mA}$ $I_F=10\text{mA}$
Reverse Current	$I_R$		0.5	2.0	$\mu\text{A}$	$V_R=25\text{V}$
Diode Capacitance	$C_d$		7.6	10	pF	$V_R=1\text{V}, f=1\text{MHz}$
Reverse Recovery Time	$t_{rr}$			5	ns	$I_F=I_R=10\text{mA}$



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## Typical Electrical Characteristic Curves

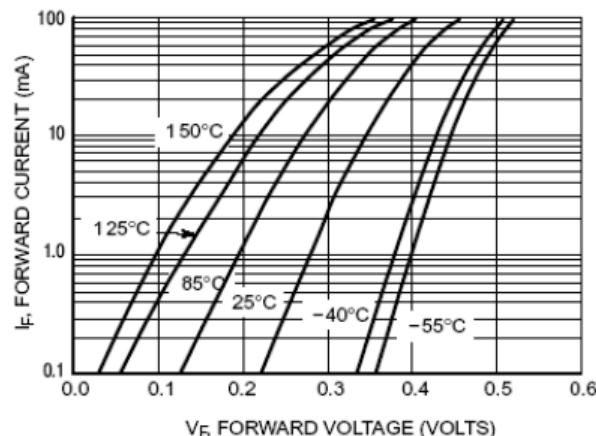


Figure 1. Forward Voltage

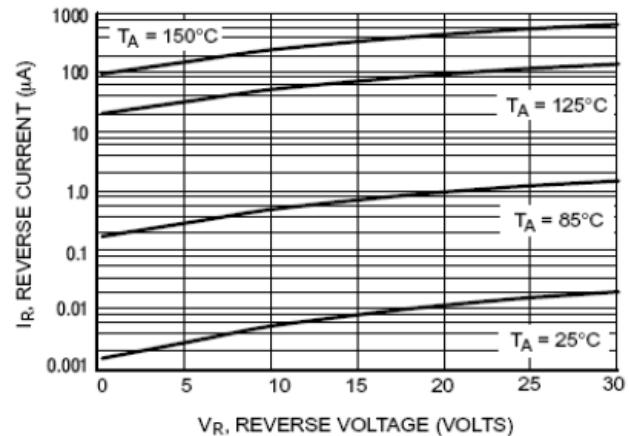


Figure 2. Leakage Current

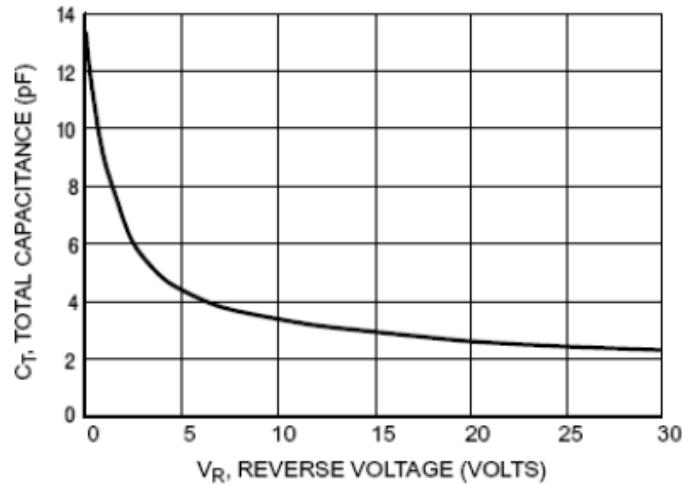


Figure 3. Total Capacitance



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## Package Outline Dimensions SOD-523

SOD-523		
Dim	Min	Max
A	1.1	1.3
B	0.7	0.9
C	0.5	0.7
D	0.3 Typical	
E	0.15	0.25
J	0.1 Typical	
K	1.5	1.7
All Dimensions in mm		

## Marking and Ordering Information

Device	Package	Carrier	Quantity	Marking
SPBAT54X	SOD-523	Tape & Reel	8,000pcs / Reel	JV